

Application toolkit EPCOS SAW resonators and frontend filters

info.ae@epcos.com www.epcos.com/rke (find application notes, S parameters...) Edition 2005



Applications for SAW resonators and frontend filters

Automotive



Remote keyless entry



Tire pressure monitoring



Security and access



Fire/burglar alarm



Access control and tagging

Home comfort



Wireless switches



Meter reading



Garage door opener



Wireless audio



SAW automotive electronics

Customer benefits

- Complete range of resonators and frontend filters for all standard frequencies and IF concepts
- SAW resonators with tight frequency tolerances: ±50 kHz / ±75 kHz / ±100 kHz
- Most sophisticated wide band, narrow band and ultra narrow band SAW frontend filters worldwide
- Hermetically sealed SMD package for flawless performance in extremely hostile environments
- Enhanced reliability (particle protection) and reduced aging by patented PROTEC[®] and ELPAS technologies
- Proven and certified reliability complying with stringent QA requirements of the automotive industry worldwide (ISO/TS 16949, AEC-Q200)









The piezoelectrical effect



The piezoelectrical effect describes the transformation of **mechanical energy** into electrical energy and vice versa



InterDigital Transducer (IDT)



The electromechanical energy conversion via surface acoustic wave (SAW) takes place in the Interdigital Transducer (IDT). Therefore, the IDT acts as:

- Transmitter: reverse piezoelectric effect
- Receiver: piezoelectric effect

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Maximum coupling strength for $I_{SAW} = v_{SAW} / f = 2 \cdot p$

- → electric RF field generates SAW
- → SAW generates electric RF field



Basics on <u>Surface Acoustic Wave</u>

For Rayleigh waves: Elliptical particle trajectory

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- Depth of penetration about 1 wavelength
- v_{SAW} » 3000 m/s » 10⁻⁵ v_{Light} At the same frequency, the wave length is 10⁻⁵ times less than for electromagnetic waves
- Typical values for I: at 246 MHz 12 mm at 900 MHz 4 mm at 1,800 MHz 2 mm
- Principles of wave guide and antenna theories can be used to describe SAWs

Function of a SAW component made visible: REM picture



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How SAW resonators and frontend filters work



The SAW chip is a piezoelectric single crystal (e.g. quartz, lithium tantalate, lithium niobate), polished on the surface and coated with one or more comb-like, interlocking electrode fingers, so-called interdigital transducers. These usually consist of aluminum and are deposited by photolithographic means. When an electric signal is applied to an electrical transducer, an electrical field is produced between the differently polarized transducer fingers and, because of the (reverse) piezoelectric effect, the chip surface is deformed mechanically. Like tiny seismic waves, a surface acoustic wave spreads out from both sides of the transducer. The reflectors on both sides of the transducer reflect these acoustic waves and thus create a standing wave, which is converted back into an electrical signal at an output transducer (piezoelectric effect).



How SAW frontend filters work



SAW filters are very flexible concerning design: Frequency and bandwidth can be determined by:

- the spacing of the transducer fingers
- their number
- substrate
- design technique

If the wave length corresponds to the finger spacing, there is a constructive otherwise destructive - superimposion of the surface waves. The result is, put simply, the characteristic bandpass response of SAW filters.



How SAW resonators work



In an oscillator circuit (e.g. Pierce or Colpitts oscillator) the ambient thermal noise is being amplified and fed back through the feedback loop into the oscillator system. A built-in SAW resonator attenuates most of this noise spectrum, only a very narrow frequency band can pass:

If the wave length corresponds to the finger spacing and resonance occurs, there is a constructive - otherwise destructive - superimposion of the surface waves. As a result, due to the resonator's position in the feedback loop of the oscillator, only the noise portion which closely match the resonator's resonance frequency, will be amplified, thus creating a very exact oscillation frequency of the oscillator.



One port resonator and equivalent circuit





- R₁ = motional resistance
- = motional inductance L_1 C_1
 - = motional capacitance
- C_0 = static capacitance



Architecture of a SAW resonator stabilized remote control transmitter



The code which is supposed to be transmitted to the receiver consists of an encoded identifier (including a rolling code for security reasons) and the message itself to e.g. unlock the central locking system of a car.

An oscillator which is synchronized by a SAW resonator oscillates at an exact frequency. Thereby, it generates an RF carrier signal, which (using the simple on-off-keying procedure, OOK) is modulated according to the transmission code by simply turning the oscillator on and off. This coded, modulated RF signal will be sent out through the antenna of the transmitter.



Architecture of a SAW resonator stabilized remote control receiver with SAW frontend filter



The modulated RF signal (encoded message) sent from the transmitter is received by the antenna of the receiver a few feet away (typically 30 to 300 ft.). Additionally, the receiver will involuntarily pick up environmental noise and spurious emissions which may jam/block the receiver, making it deaf for any message from the transmitter. To avoid this, a narrow band SAW frontend filter with high selectivity can filter out this unwanted noise.

A local oscillator (stabilized e.g. by a SAW resonator like the transmitter oscillator) generates an LO frequency, typically 500 kHz or 10.7 MHz below transmission frequency. The filtered RF signal from the antenna will now be mixed down in a mixer with this LO frequency to an intermediate frequency (IF), which can be decoded by decoder ICs and microcontrollers.



Principles of a superheterodyne receiver





How to read the filter curve of a frontend filter: Quarz substrate





How to read the filter curve of a frontend filter: Lithium tantalate substrate





Temperature dependence of a quartz filter

Characteristics						
Reference temperature:	TA	= 25 °C)		1 A	
Terminating source impedance:	Terminating source impedance: $Z_{\rm S} = 50 \Omega$ and matching network					
Terminating load impedance:	Z_{L}	= 50 Ω and matching network				
			min.	typ.	max.	
Center frequency		fC	- 1	868,39	_	MHz
(center frequency between 3 dB points)						
Minimum insertion attenuation		α _{min}				
868,00 868,78	MHz		_	2,7	4,2	dB
Pass band (relative to α_{min})						
868,00 868,78	MHz		_	1,0	3,0	dB
867,90 868,88	MHz		_	1,5	6.0	dB
					- / -	
Characteristics						
Characteristics Reference temperature:	T _A	= -45 .	90 °C			
Characteristics Reference temperature: Terminating source impedance:	T_A Z_S	= -45 . = 50 Ω	90 °C and match	ning networ	k	л.
Characteristics Reference temperature: Terminating source impedance: Terminating load impedance:	T _A Z _S ZL	= -45 . = 50 Ω = 50 Ω	90 °C and match and match	ning networ	k k	
Characteristics Reference temperature: Terminating source impedance: Terminating load impedance:	T _A Z _S Z _L	= -45 . = 50 Ω = 50 Ω	90 *C and match and match	ning networ ning networ	k k	
Characteristics Reference temperature: Terminating source impedance: Terminating load impedance:	T _A Z _S Z _L	= -45 . = 50 Ω = 50 Ω	90 °C and match and match	ning networ ning networ	k k max.	
Characteristics Reference temperature: Terminating source impedance: Terminating load impedance: Center frequency	T _A Z _S Z _L	= -45 . = 50 Ω = 50 Ω	90 °C and match and match min.	ning networ ning networ typ. 868,30	k k max.	MHz
Characteristics Reference temperature: Terminating source impedance: Terminating load impedance: Center frequency (center frequency between 3 dB points)	T _A Z _S Z _L	= -45 . = 50 Ω = 50 Ω	90 °C and match and match min.	ning networ ning networ typ. 868,30	k k max. 	MHz
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Characteristics Reference temperature: Terminating source impedance: Terminating load impedance: Center frequency (center frequency between 3 dB points) Minimum insertion attenuation 868,00 868,70 Pass band (relative to quere)	T _A Z _S Z _L	$= -45 .$ $= 50 \Omega$ $= 50 \Omega$ f_c α_{min}	90 °C and match and match min. —	ning networ ning networ typ. 868,30 2,7	k k — 4,7	dB
Characteristics Reference temperature: Terminating source impedance: Terminating load impedance: Center frequency (center frequency between 3 dB points) Minimum insertion attenuation 868,00 868,70 Pass band (relative to α _{min}) 868,00 868,60	T _A Z _S Z _L 3 MHz	$= -45 .$ $= 50 \Omega$ $= 50 \Omega$ f_c α_{min}	90 °C e and match and match min. — —	ning networ ning networ typ. 868,30 2,7	k k <u>max.</u> 4,7	MHz dB
Characteristics Reference temperature: Terminating source impedance: Terminating load impedance: Center frequency (center frequency between 3 dB points) Minimum insertion attenuation 868,00	T _A Z _S Z _L 3 MHz	$= -45 .$ $= 50 \Omega$ $= 50 \Omega$ f_c α_{min}	90 °C e and match and match min. — — —	hing networ hing networ 868,30 2,7 1,0	k k <u>max.</u> 4,7	dB dB

$$f_C(T_A) = f_C(T_0) (1 + TC_f(T_A - T_0)^2)$$



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Temperature coefficient of quartz substrate



 Quartz has a parabolic temperature behaviour: TC_f = -0.03 ppm/K²

- The inversion point T₀ can be adjusted by choice of the appropiate cut and metallisation height and ratio (usually: 25 °C)
- Every deviation from T0 leads to a down shift of the center frequency

$$f_C(T_{\mathsf{A}}) = f_C(T_0) \; (1 + TC_{\mathsf{f}}(T_{\mathsf{A}} - T_0)^2)$$

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How to calculate the <u>total tolerance over</u> <u>temperature</u> of a SAW resonator



Quartz has a square temperature characteristic and a negative temperature coefficient of -0.03. Therefore a change in temperature always results in a drop of center frequency. For worst case calculation, this frequency shift due to temperature needs to be added to the manufacturing tolerances (=m.tolerance, typ. +-75 kHz). The total tolerance over temperature of a SAW resonator needs to be calculated: $2f = (2 \times m.tolerance) + (frequency shift at max/min temperature).$ (see example!)



How to calculate total tolerance of a SAW resonator and filter



Transmitters and receivers may have different temperatures (e.g. transmitter in the car key: room temperature. Receiver in the car in winter: -20 °C). Therefore for worst case calculation, the minimum bandwidth of the filter has to take into account both the <u>resonator's total</u> tolerance over temperature and *filter's frequency shift over temperature*.

The left drawing shows the *frequency shift over temperature of a filter* and the resulting usable (or guaranteed) bandwidth. In order to work properly, the <u>resonator's total tolerance</u> <u>over temperature</u> in the right drawing needs to be inside the filter's guaranteed bandwidth over temperature everywhere.



Worldwide frequency regulations

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European duty cycled SRD band 868 to 870 MHz



European SRD bands 433.92 MHz and 869 MHZ: Most important sources of interference





Laser marking on ceramic SMD packages





Comparison of frontend filters

Wide band, narrow band, ultra-narrow band





Product portfolio: Frontend filters



- Bandwidth
- Substrate
- Passivation
- Input/output imp.
- Temperature shift
- Package
- Insertion loss
- Nearby selectivity
- Overall selectivity
- Remark

20 Ð 2 Wide band Lithium tantalate **ELPAS** 50 Ohms matched

-- high

- low

+ very good

applications

DCC6C, 3.0x3.0

QCC8B, 3.8x3.8mm

mainly used for non-

automotive applications;

easy and cheap to match -> perfect for low-cost

++ especially good



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Normalized frequency response (wideband

- Narrow band Quartz PROTEC / ELPAS
 - >>50 Ohms
 - ++ low
 - QCC8B, 3.8x3.8mm
 - QCC8C, 5x5mm
 - + best on the market
 - + high
 - + verv good
 - necessary for automotive applications in Europe, ++ well suited for TPMS



- Ultra-narrow band
- Quartz
- PROTEC
- >>50 Ohms
 - ++ low
 - **QCC8C**, 5x5mm
 - o not main focus
- ++ very high
- ++ very good
- too narrow for SAW res.
 - -- needs ext. coupling coil



Product portfolio: 3 resonator platforms

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Product portfolio: GPS filter for automotive applications



Package

- Temperature range _ -40 to 105 °C specified -40 to 125 °C operable
- Input/output imp. 50 Ohm / 50 Ohm unbal./unbal.
- Features _____ Low insertion loss
- Qualification _____ AEC/Q-200 (in progress)

B3520

DCC6C (3x3mm²)

Metal ceramic SMD



QCC8D



B4059/B3521 QCC8D (3x3mm²) Metal ceramic SMD -40 to 105 °C specified -40 to 125 °C operable 50 Ohm / 50 Ohm unbal./unbal. High selectivity at AMPS and GSM AEC/Q-200 (in progress)

B4060 QCC8D (3x3mm²) Metal ceramic SMD -40 to 105 °C specified -40 to 125 °C operable

- _ 50 Ohm / 50 Ohm unbal./bal.
- Low insertion loss

High power durability AEC/Q-200 (in progress)



All EPCOS divisions at a glance



Products by divisions

Capacitors	Film Capacitors	Inductors	
 Aluminum electrolytic capacitors Tantalum capacitors Polymer capacitors Ultracapacitors 	Film capacitorsPower capacitors	 Transformers & chokes RF chokes EMC filters 	
	SAW Components		
Ceramic Components	 Microwave ceramics & modules 	Ferrites	
 Sensors & sensor elements Ceramic semiconductors Multilayer ceramic technology Piezo technology Surge arresters Switching spark gaps 	 Crystals for acoustic & optical components Components for Mobile communications Multimedia applications Consumer electronics Automotive electronics 	 Ferrites Accessories 	

Key components for future applications



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Abbreviations

- SAW Surface Acoustic Wave
- **RKE** Remote Keyless Entry
- PLL Phase Locked Loop
- **ASK** Amplitude Shifted Keying
- **FSK** Frequency Shifted Keying
- **IDT** Interdigital Transducer
- **RF** Radio Frequency
- **OOK** On/Off Keying = Amplitude Modulation
- LO Local Oscillator
- IF Intermediate Frequency, achieved by superposition of two slightly different oscillators
- LNA Low Noise Amplifier
- **SRD** Short Range Device
- **LT** Lithium Tantalate (LiTaO³)
- **LN** Lithium Niobate (LiNbO³)
- **CW** Continuos Wave
- TX Transmitter
- **RX** Receiver
- **Duty** Cycle Ratio between On time and Off time